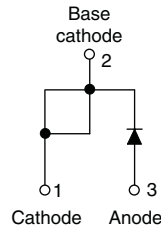


## Fast Soft Recovery Rectifier Diode, 20 A



TO-220AC



### FEATURES/DESCRIPTION

The 20ETF..PbF fast soft recovery rectifier series has been optimized for combined short reverse recovery time and low forward voltage drop.

The glass passivation ensures stable reliable operation in the most severe temperature and power cycling conditions.

This product series has been designed and qualified for industrial level and lead (Pb)-free.



**RoHS\***  
COMPLIANT

PRODUCT SUMMARY	
$V_F$ at 20 A	< 1.31 V
$I_{FSM}$	355 A
$V_{RRM}$	800 to 1200 V

### APPLICATIONS

- Output rectification and freewheeling in inverters, choppers and converters
- Input rectifications where severe restrictions on conducted EMI should be met

MAJOR RATINGS AND CHARACTERISTICS			
SYMBOL	CHARACTERISTICS	VALUES	UNITS
$V_{RRM}$		800 to 1200	V
$I_{F(AV)}$	Sinusoidal waveform	20	A
$I_{FSM}$		355	
$t_{rr}$	1 A, 100 A/ $\mu$ s	95	ns
$V_F$	20 A, $T_J = 25^\circ\text{C}$	1.31	V
$T_J$	Range	- 40 to 150	$^\circ\text{C}$

VOLTAGE RATINGS			
PART NUMBER	$V_{RRM}$ , MAXIMUM PEAK REVERSE VOLTAGE V	$V_{RSM}$ , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	$I_{RRM}$ AT 150 $^\circ\text{C}$ mA
20ETF08PbF	800	900	6
20ETF10PbF	1000	1100	
20ETF12PbF	1200	1300	

ABSOLUTE MAXIMUM RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum average forward current	$I_{F(AV)}$	$T_C = 97^\circ\text{C}$ , 180 $^\circ$ conduction half sine wave	20	A
Maximum peak one cycle non-repetitive surge current	$I_{FSM}$	10 ms sine pulse, rated $V_{RRM}$ applied	300	
		10 ms sine pulse, no voltage reapplied	355	
Maximum $I^2t$ for fusing	$I^2t$	10 ms sine pulse, rated $V_{RRM}$ applied	450	$\text{A}^2\text{s}$
		10 ms sine pulse, no voltage reapplied	635	
Maximum $I^2\sqrt{t}$ for fusing	$I^2\sqrt{t}$	$t = 0.1$ to 10 ms, no voltage reapplied	6350	$\text{A}^2\sqrt{\text{s}}$

\* Pb containing terminations are not RoHS compliant, exemptions may apply

# 20ETF..PbF Soft Recovery Series

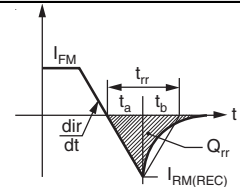


Vishay High Power Products

Fast Soft Recovery  
Rectifier Diode, 20 A

ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop	$V_{FM}$	20 A, $T_J = 25\text{ }^\circ\text{C}$		1.31	V
Forward slope resistance	$r_t$	$T_J = 150\text{ }^\circ\text{C}$		11.88	$\text{m}\Omega$
Threshold voltage	$V_{F(TO)}$			0.93	V
Maximum reverse leakage current	$I_{RM}$	$T_J = 25\text{ }^\circ\text{C}$	$V_R = \text{Rated } V_{RRM}$	0.1	mA
		$T_J = 150\text{ }^\circ\text{C}$		6	

RECOVERY CHARACTERISTICS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Reverse recovery time	$t_{rr}$	$I_F$ at 20 Apk 25 A/ $\mu\text{s}$ 25 $^\circ\text{C}$	400	ns
Reverse recovery current	$I_{rr}$		6.1	A
Reverse recovery charge	$Q_{rr}$		1.7	$\mu\text{C}$
Snap factor	S	Typical	0.6	



THERMAL - MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range	$T_J, T_{Stg}$		- 40 to 150	$^\circ\text{C}$
Maximum thermal resistance, junction to case	$R_{thJC}$	DC operation	0.9	$^\circ\text{C}/\text{W}$
Maximum thermal resistance, junction to ambient	$R_{thJA}$		62	
Typical thermal resistance, case to heatsink	$R_{thCS}$	Mounting surface, smooth and greased	0.5	
Approximate weight			2	g
			0.07	oz.
Mounting torque	minimum		6 (5)	$\text{kgf} \cdot \text{cm}$ ( $\text{lbf} \cdot \text{in}$ )
	maximum		12 (10)	
Marking device		Case style TO-220AC	20ETF08	

# 20ETF..PbF Soft Recovery Series

Vishay High Power Products

Fast Soft Recovery  
Rectifier Diode, 20 A

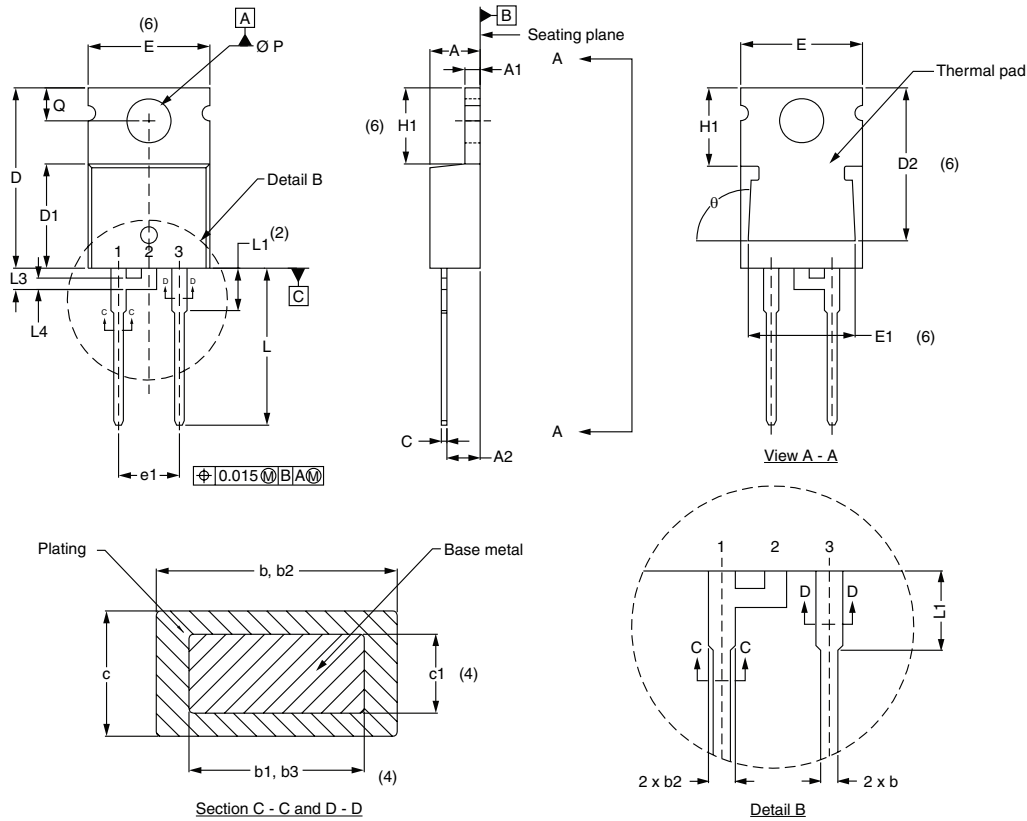


## ORDERING INFORMATION TABLE

Device code	20	E	T	F	12	PbF
	①	②	③	④	⑤	⑥
①	-	Current rating (20 = 20 A)				
②	-	Circuit configuration:				
		E = Single diode				
③	-	Package:				
		T = TO-220AC				
④	-	Type of silicon:				
		F = Fast soft recovery rectifier				
⑤	-	Voltage ratings				
						08 = 800 V 10 = 1000 V 12 = 1200 V
⑥	-	• None = Standard production				
		• PbF = Lead (Pb)-free				

## TO-220AC

### DIMENSIONS in millimeters and inches



SYMBOL	MILLIMETERS		INCHES		NOTES
	MIN.	MAX.	MIN.	MAX.	
A	3.56	4.82	0.140	0.190	
A1	0.51	1.40	0.020	0.055	
A2	2.04	2.92	0.080	0.115	
b	0.38	1.01	0.015	0.040	
b1	0.38	0.96	0.015	0.038	4
b2	1.15	1.77	0.045	0.070	
b3	1.15	1.73	0.045	0.068	4
c	0.36	0.61	0.014	0.024	
c1	0.36	0.56	0.014	0.022	4
D	14.22	15.87	0.560	0.625	3
D1	8.38	9.02	0.330	0.355	
D2	12.19	12.88	0.480	0.507	6

SYMBOL	MILLIMETERS		INCHES		NOTES
	MIN.	MAX.	MIN.	MAX.	
E	9.66	10.66	0.380	0.420	3, 6
E1	8.38	8.89	0.330	0.350	6
e	2.54 BSC		0.100 BSC		
e1	5.08 BSC		0.200 BSC		
H1	5.85	6.86	0.230	0.270	6
L	12.70	14.73	0.500	0.580	
L1	-	6.35	-	0.250	2
L3	1.78	2.13	0.070	0.084	
L4	0.76	1.27	0.030	0.050	
Ø P	3.54	3.73	0.139	0.147	
Q	2.54	3.05	0.100	0.120	
θ	90° to 93°		90° to 93°		

#### Notes

- (1) Dimensioning and tolerancing per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3 and c1 apply to base metal only
- (5) Controlling dimensions: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2 and E1
- (7) Outline conforms are derived from the actual package outline